

Course guide 2301202 - SFDM - Semiconductor and Device Manufacturing Facilities

Last modified: 29/05/2025

Unit in charge: Barcelona School of Telecommunications Engineering **Teaching unit:** 710 - EEL - Department of Electronic Engineering.

Degree: MASTER'S DEGREE IN SEMICONDUCTOR ENGINEERING AND MICROELECTRONIC DESIGN (Syllabus 2024).

(Optional subject).

Academic year: 2025 ECTS Credits: 6.0 Languages: English

LECTURER

Coordinating lecturer: DAVID QUIRION

Others: Primer quadrimestre:

JUAN DE DIOS CASTILLO MACHICADO - 11

ALBERTO DEL MORAL CEJUDO - 11

MARIA MANNA - 11

GERARD MASMITJÀ RUSIÑOL - 11 JOAOUIN PUIGDOLLERS GONZALEZ - 11

DAVID QUIRION - 11

FRANCESC TORRES CANALS - 11 CRISTOBAL VOZ SANCHEZ - 11 MIGUEL ZABALA GARCÍA - 11

PRIOR SKILLS

Microelectronic Technologies and Processes, Microelectronic design

LEARNING RESULTS

Knowledges:

KT01. Identify semiconductor devices, technological processes, the most appropriate microelectronic design tools, and relationships between these elements in order to integrate a given product or system into microelectronic technologies.

KT03. Describe the physical principles underlying current semiconductor devices in relation to their application, as well as their emerging trends, modelling and characterisation techniques.

KT04. Identify and describe the different manufacturing and characterisation processes in microelectronics and their applicability according to the functional and cost requirements of the final integrated product.

KT07. Identify gender stereotypes and roles and how they may impact professional practice.

Skills

ST06. Plan the different activities involved in successfully carrying out an assigned task within a team, managing time and resources appropriately.

Competences:

CT03. Apply the processes of semiconductor engineering and microelectronic design to fields in diverse areas of science or engineering where integrated systems are required.

TEACHING METHODOLOGY

Expository method, participatory lecture, problem-based learning and case studies

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LEARNING OBJECTIVES OF THE SUBJECT

- 1. Explore cleanroom facilities, equipment, safety protocols, operation, and impact on the environment.
- 2. Acquire practical knowledge of microelectronic processes and access to external foundries for the manufacture of semiconductor devices.
- 3. Know how to identify and apply cleanroom technological processes for the manufacture of devices and integrated circuits.
- 4. Characterise and identify critical aspects in process integration to maximise the likelihood of success in a complete cleanroom manufacturing process.
- 5. Develop critical thinking and problem-solving skills relevant to semiconductor manufacturing, especially oriented to process integration.

STUDY LOAD

Туре	Hours	Percentage
Self study	102,0	68.00
Hours small group	36,0	24.00
Hours large group	12,0	8.00

Total learning time: 150 h

CONTENTS

Cleanroom facilities

Description:

- 1. Context: why do we need a cleanroom? Concept of contamination in microelectronics. Cleanroom classifications and standards.
- 2. Installations: Cleanroom design principles and environmental controls. Filtration, air contamination. Temperature, humidity, and overpressure control. Services: ultra-pure water, vacuum system, gas distribution.
- 3. Working in a cleanroom: Behaviour and prevention of occupational hazards. Safety protocols and contamination control measures. Wafer handling. Basic concepts of yield.
- 4. The clean room and its environment: Sustainability and environmental issues.

Full-or-part-time: 8h Theory classes: 8h

Manufacturing

Description:

- 1. Introduction to the clean room (UPC or IMB-CNM): safety protocols/ locker room/ internal visit to different rooms/ + one/s small experiment/s (e.g. wafer cutting).
- 2. Basic processes I: wafer cleaning (RCA1/RCA2)/oxidation (UPC)
- 3. Basic Processes II: lithography/wet etching (UPC)
- 4. Basic Processes III: Diffusion/Deposition (ALD or sputtering or PECVD) (UPC)
- 5. Site visit (IMB-CNM)

Full-or-part-time: 25h Laboratory classes: 25h

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Introduction to external foundries

Description:

- 1. Introduction: Access to commercial technologies. IC suppliers.
- 2. Methodology: Searching for the best technology for our purposes: coarse description of the technology. Access to design kit files.
- 3. Examples: Some examples of technology parameters and design rules: fine description of the technology.

Full-or-part-time: 3h Theory classes: 3h

Definition of a manufacturing process

Description:

- 1. Introduction to process integration.
- 2. Project work: Definition of a device manufacturing process in groups of 3-4 students: sequence of steps; equipment and recipe type; mask design; definition of test structures

Full-or-part-time: 12h Theory classes: 1h Laboratory classes: 11h

GRADING SYSTEM

Course work (10%), mini-project (block 4 20%) plus exam (70%)

BIBLIOGRAPHY

Basic:

- Whyte, W. Cleanroom technology: fundamentals of design, testing and operation. 3rd ed. W. Whyte, 2023. ISBN 9798370511592.
- Xiao, H. Introduction to semiconductor manufacturing technology [on line]. 2nd ed. Bellingham, Wash.: SPIE, 2012 [Consultation: 14/06/2024]. Available on:

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- Ohring, M.; Gall, D.; Baker, S.P. Materials science of thin films [on line]. 2nd ed. Elsevier Science & Technology Books, 2002 [Consultation: 13/06/2024]. Available on: https://www-sciencedirect-com.recursos.biblioteca.upc.edu/book/9780125249751/materials-science-of-thin-films. ISBN 9780125249751.
- Quirk, M.; Serda, J. Semiconductor manufacturing technology. Upper Saddle River: Prentice Hall, 2001. ISBN 9780130815200.
- Wolf, S. Silicon processing for the VLSI era. Vol.2: process integration. Sunset Beach: Lattice, 1990. ISBN 0961672145.

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